Vishay High Power Products

Phase Control Thyristors (Hockey PUK Version), 960 A

FEATURES

- · Center amplifying gate
- · Metal case with ceramic insulator
- International standard case TO-200AB (E-PUK)
- profile hockey Low PUK to increase current-carrying capability
- · Lead (Pb)-free
- · Designed and qualified for industrial level

TYPICAL APPLICATIONS

- · DC motor controls
- · Controlled DC power supplies
- · AC controllers

MAJOR RATINGS AND CHARACTERISTICS							
PARAMETER	TEST CONDITIONS	VALUES	UNITS				
1		960	A				
I _{T(AV)}	T _{hs}	55	٥C				
1		1900	А				
I _{T(RMS)}	T _{hs}	25	°C				
I _{TSM}	50 Hz	15 000	٨				
	60 Hz	15 700	A				
l ² t	50 Hz	1130	kA ² s				
1-1	60 Hz	1030	KA-S				
V _{DRM} /V _{RRM}		400/600	V				
t _q	Typical	100	μs				
TJ		- 40 to 125	°C				

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS										
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$I_{DRM}/I_{RRM} MAXIMUM AT T_J = T_J MAXIMUM mA$						
ST380CC	C 04 400		500	50						
06		600	700							

For technical questions, contact: ind-modules@vishay.com



SHA



TO-200AB (E-PUK)

PRODUCT SUMMARY

I_{T(AV)}

960 A

Document Number: 94410

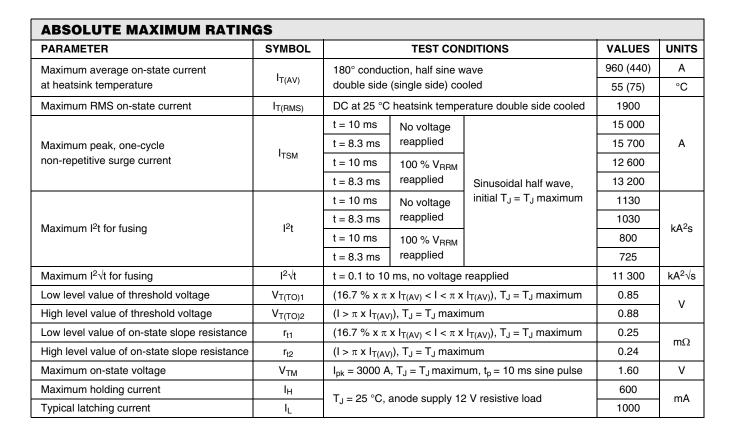
Revision: 11-Aug-08

RoHS

COMPLIANT

ST380CPbF Series

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SWITCHING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega, t_r \leq$ 1 μs T_J = T_J maximum, anode voltage \leq 80 % V_{DRM}	1000	A/µs				
Typical delay time	t _d	Gate current 1 A, dl _g /dt = 1 A/ μ s V _d = 0.67 % V _{DRM} , T _J = 25 °C	1.0					
		I_{TM} = 550 A, T _J = T _J maximum, dl/dt = 40 A/μs, V _R = 50 V, dV/dt = 20 V/μs, gate 0 V 100 Ω, t _p = 500 μs	100	μs				

BLOCKING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated V_{DRM}	500	V/µs				
Maximum peak reverse and off-state leakage current	I _{RRM,} I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	50	mA				



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TRIGGERING							
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES		
PARAMETER	STMBUL	SYMBOL TEST CONDITIONS		TYP.	MAX.	UNITS	
Maximum peak gate power	P _{GM}	$T_J = T_J$ maximum,	t _p ≤ 5 ms	10.0		w	
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	vv	
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum,	t _p ≤ 5 ms	3	.0	А	
Maximum peak positive gate voltage	+ V _{GM}		t < 5 mg	20		v	
Maximum peak negative gate voltage - V		ij = ij maximum,	$T_J = T_J$ maximum, $t_p \le 5$ ms			v	
		T _J = - 40 °C		200	-		
DC gate current required to trigger	I _{GT}	T _J = 25 °C	Maximum required gate trigger/	100	200	mA	
		T _J = 125 °C	current/voltage are the lowest	50	-		
		T _J = - 40 °C	value which will trigger all units	2.5	-		
DC gate voltage required to trigger	V_{GT}	T _J = 25 °C	12 V anode to cathode applied	1.8	3.0	V	
		T _J = 125 °C		1.1	-		
DC gate current not to trigger	I _{GD}	$T_{.1} = T_{.1}$ maximum	Maximum gate current/voltage not to trigger is the maximum value which will not trigger any	10		mA	
DC gate voltage not to trigger	V _{GD}	ij = ij maximum	unit with rated V _{DRM} anode to cathode applied	0.25		v	

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum operating junction temperature range	TJ		- 40 to 125	°C			
Maximum storage temperature range	T _{Stg}		- 40 to 150	- °C			
Movimum thermal registered junction to bestainly	Р	DC operation single side cooled	0.09				
Maximum thermal resistance, junction to heatsink	R_{thJ-hs}	DC operation double side cooled	0.04	к/w			
Maximum thermal registeres, asso to bestainly	R _{thC-hs}	DC operation single side cooled					
Maximum thermal resistance, case to heatsink		DC operation double side cooled	0.01	1			
Mounting force, ± 10 %			9800 (1000)	N (kg)			
Approximate weight			83	g			
Case style		See dimensions - link at the end of datasheet	TO-200AB (E-PUK)			

CONDUCTION ANGLE	SINUSOIDAL	CONDUCTION	RECTANGULAR CONDUCTION		TEST CONDITIONS			
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	LE SIDE DOUBLE SIDE TEST CONDITIONS		UNITS		
180°	0.010	0.011	0.007	0.007				
120°	0.012	0.012	0.012	0.013				
90°	0.015	0.015	0.016	0.017	$T_J = T_J$ maximum	K/W		
60°	0.022	0.022	0.023	0.023				
30°	0.036	0.036	0.036	0.037				

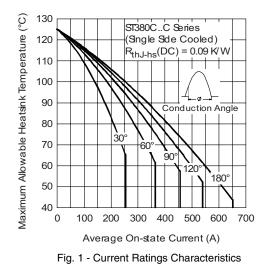
Note

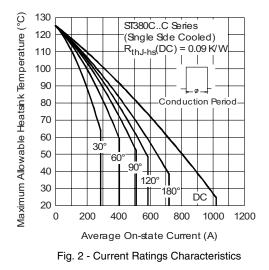
• The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

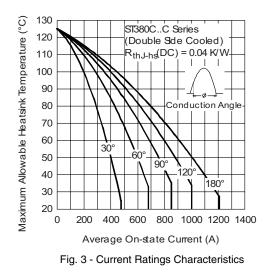
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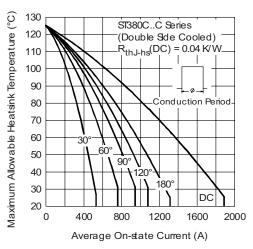
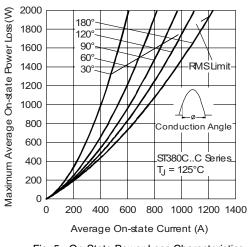
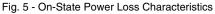


Fig. 4 - Current Ratings Characteristics





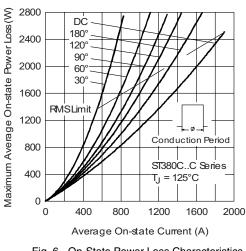
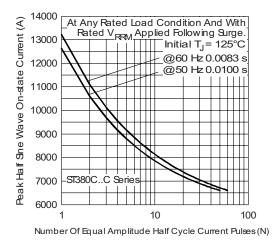


Fig. 6 - On-State Power Loss Characteristics



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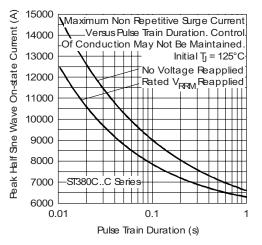


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

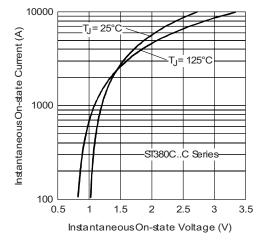


Fig. 9 - On-State Voltage Drop Characteristics

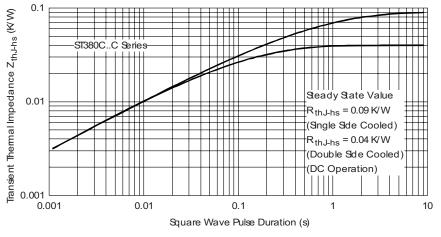


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics

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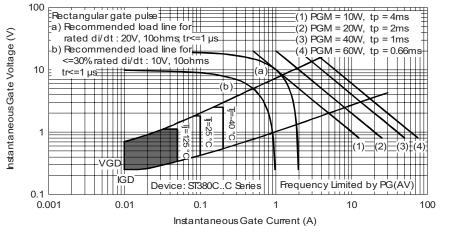


Fig. 11 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code	ST	38	0	с	06	С	1	-	PbF
		2	3	4	5	6	7	8	9
	1 -	Thy	ristor						
	2 -	Ess	ential pa	art num	ber				
	3 -	0 =	Conver	ter grade	е				
	4 -	C =	Cerami	c PUK					
	5 -	Volt	Voltage code x 100 = V _{RRM} (see Voltage Ratings table)						
	6 -	C =	C = PUK case TO-200AB (E-PUK)						
	7 -	0 =	0 = Eyelet terminals (gate and auxiliary cathode unsoldered lead						
		1 =	1 = Fast-on terminals (gate and auxiliary cathode unsoldered lea						
		2 =	2 = Eyelet terminals (gate and auxiliary cathode soldered leads)						
	_	3 =	3 = Fast-on terminals (gate and auxiliary cathode soldered leads						
	8 -	Crit	ical dV/	dt: • No	ne = 50	0 V/µs (standa	rd selec	tion)
	_			• L =	: 1000 V	∕/µs (sp	ecial se	lection)	
	9 -	Lea	ld (Pb)-f	ree					

LINKS TO RELATED DOCUMENTS						
Dimensions http://www.vishay.com/doc?95075						
	•					



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